# 1H1G thru 1H8G



Glass Passivated High Efficient Rectifiers Reverse Voltage 50 to 1000 Volts Forward Current 1.0 Ampere

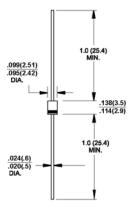
## **Features**

- < Low forward voltage drop
- High current capability
- High reliability
- High surge current capability

## R-1

## **Mechanical Data**

- Case: Molded plastic R-1
- < Epoxy: UL 94V-O rate flame retardant
- < Lead: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity: Color band denotes cathode end
- High temperature soldering guaranteed: 250°C/10 seconds .375" (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- Mounting position: Any
  Weight: 0.007 ounce, 0.20 gram



## Dimensions in inches and (millimeters)

## **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Parameter	Symbols	1H1G	1H2G	1H3G	1H4G	1H5G	1H6G	1H7G	1H8G	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	Volts
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	300	400	600	800	1000	Volts
Maximum average forward rectified current .375" (9.5mm) lead length @T <sub>A</sub> =55°C	I <sub>(AV)</sub>	1.0								Amp
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	30.0								Amps
Maximum instantaneous forward voltage @ 1.0A	V <sub>F</sub>	1.0 1.3 1.7					Volts			
Maximum DC reverse current @ T = 25°C at rated DC blocking voltage @ T = 125°C	I <sub>R</sub>	5.0 100								uA uA
Maximum reverse recovery time (Note 1)	t <sub>rr</sub>	50 75						nS		
Typical junction capacitance (Note 2)	C <sub>J</sub>	20 15							pF	
Operating junction temperature range	T <sub>J</sub>	-55 to +150								°C
Storage temperature range	T <sub>STG</sub>	-55 to +150								°C

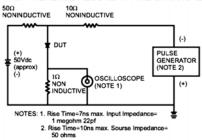
1. Reverse Recovery Test Conditions:  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_{RR}$ =0.25A

2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

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FIG.1- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



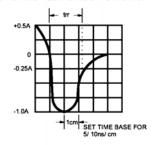


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

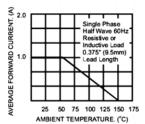


FIG.3- TYPICAL REVERSE CHARACTERISTICS

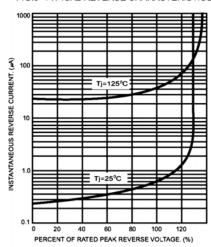
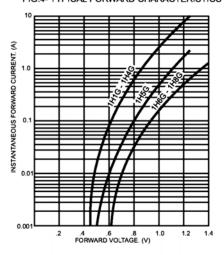


FIG.4- TYPICAL FORWARD CHARACTERISTICS



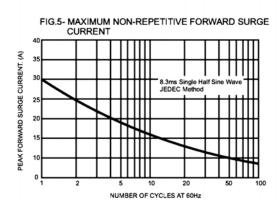
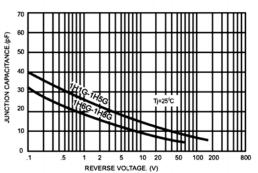


FIG.6- TYPICAL JUNCTION CAPACITANCE



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